Bulletin I2718 rev. E 05/02

International
IOR Rectifier

6GBU Series

6.0 Amps Single Phase Full Wave Bridge Rectifier

$I_{O(AV)}$ = 6A
V_{RRM} = 50/ 800V

Features

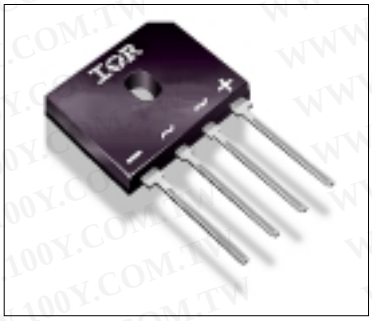
- Diode chips are glass passivated
- Suitable for Universal hole mounting
- Easy to assemble & install on P.C.B.
- High Surge Current Capability
- High Isolation between terminals and molded case (1500 V_{RMS})
- Lead free terminals solderable as per MIL-STD-750 Method 2026
- Terminals suitable for high temperature soldering at 260°C for 8-10 secs
- UL E160375 approved

Description

These GBU Series of Single Phase Bridges consist of four glass passivated silicon junction connected as a Full Wave Bridge. These four junctions are encapsulated by plastic molding technique. These Bridges are mainly used in Switch Mode power supply and in industrial and consumer equipment.

Major Ratings and Characteristics

Parameters		6GBU	Units
I_O		6	A
	@T_C	100	°C
I_{FSM}	@50Hz	175	A
	@60Hz	182	A
I^2t	@50Hz	154	A^2s
	@60Hz	138	A^2s
V_{RRM}	range	50 to 800	V
T_J		- 55 to 150	°C



6GBU

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM}, max repetitive peak rev. voltage $T_J = T_J$ max. V	V_{RMS}, max RMS voltage $T_J = T_J$ max. V	I_{RRM} max. @ rated V_{RRM} T_J = 25°C µA	I_{RRM} max. @ rated V_{RRM} T_J = 150°C µA
6GBU	005	50	35	5	400
	01	100	70	5	400
	02	200	140	5	400
	04	400	280	5	400
	06	600	420	5	400
	08	800	560	5	400

Forward Conduction

	Parameters	6GBU	Unit	Conditions	
I_O	Maximum DC output current	6.0	A	T_C = 100°C, Resistive & inductive load	
		4.8		T_C = 100°C, Capacitive load	
I_{FSM}	Maximum peak, one-cycle non-repetitive surge current, following any rated load condition and with rated V_{RRM} reapplied	175		t = 10ms	
		182		t = 8.3ms	T_J = 150°C
I^2t	Maximum I^2t for fusing, initial $T_J = T_J$ max	154	A^2s	t = 10ms	
		138		t = 8.3ms	
V_{FM}	Maximum peak forward voltage per diode	1.0	V	T_J = 25°C, I_{FM} = 6A	
I_{RM}	Typical peak reverse leakage current per diode	5.0	µA	T_J = 25°C, 100% V_{RRM}	
		400		T_J = 150°C, 100% V_{RRM}	
V_{RRM}	Maximum repetitive peak reverse voltage range	50 to 800	V		

Thermal and Mechanical Specifications

	Parameters	6GBU	Unit	Conditions
T_J T_{stg}	Operating and storage temperature range	-55 to 150	°C	
R_{thJC}	Max. thermal resistance junction to case	2.2	°C/W	DC rated current through bridge (1)
R_{thJA}	Thermal resistance, junction to ambient	7.4	°C/W	DC rated current through bridge (1)
W	Approximate weight	4 (0.14)	g (oz)	
T	Mounting Torque	1.0	Nm	Bridge to Heatsink
		9.0	Lb.in	

Note (1): Bridge mounted on Aluminum heat sink of dim 65 x 35 x 1.5mm, use silicon thermal compound heat transfer and bolt down using 3mm screw

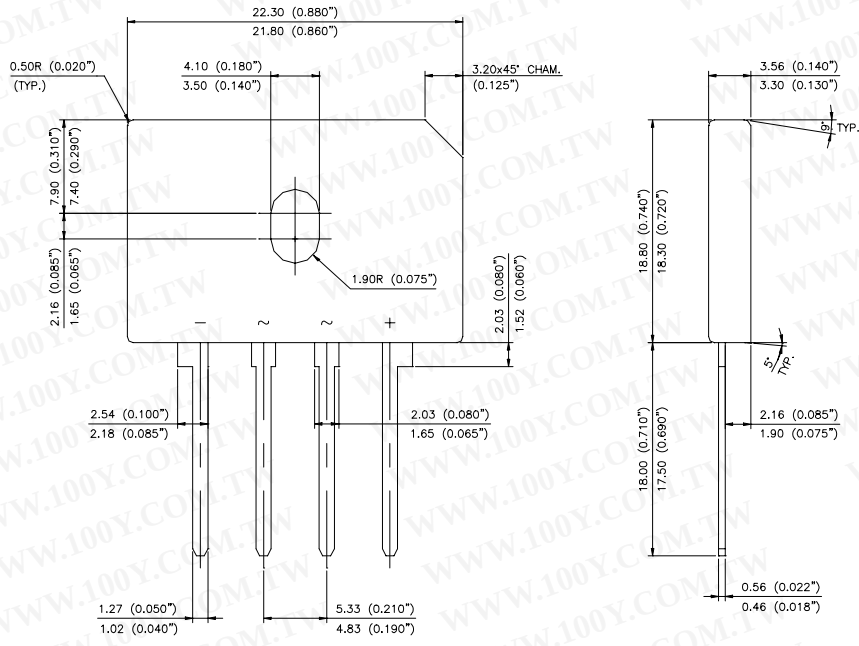
Ordering Information Table

Device Code

6	GBU	08
1	2	3

1	-	Bridge current
2	-	Basic Part Number
3	-	Voltage Code: code x 100 = V_{RRM}

Outline Table



NOTE:
1. POLARITY SHOWN ON FRONT SIDE OF CASE, POSITIVE LEAD BY BEVELED CORNER
2. ALL DIMENSIONS IN MM AND (INCHES)

All dimensions are in millimetres

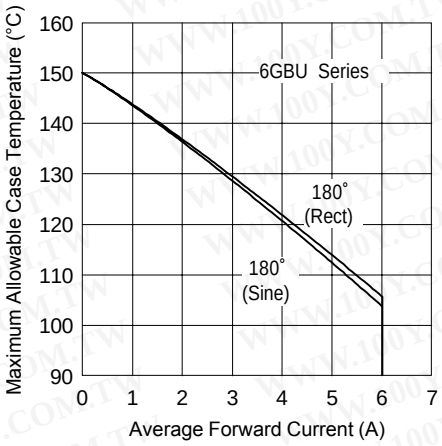


Fig. 1 - Current Ratings Characteristics

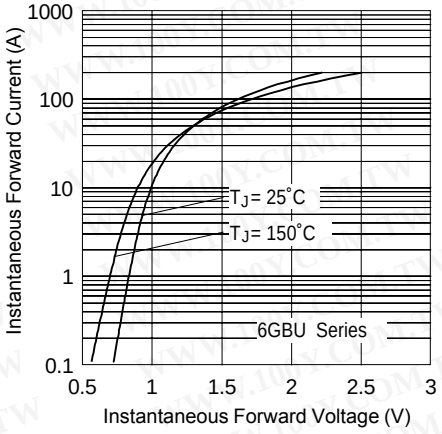


Fig. 2 - Forward Voltage Drop Characteristics

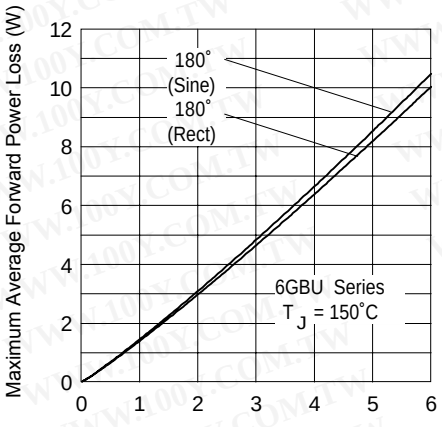


Fig. 3 - Total Power Loss Characteristics

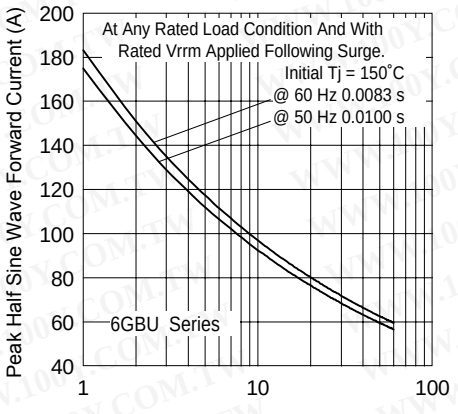


Fig. 4 - Maximum Non-Repetitive Surge Current